



**V Ukrainian -
Polish - Lithuanian
Meeting
on Physics of
Ferroelectrics**

Programme & Abstract



**18-20 September, 2018
Uzhhorod, Ukraine**

Наукове видання

Тези міжнародної науково-практичної конференції
«V УКРАЇНСЬКО-ПОЛЬСЬКО-ЛИТОВСЬКА КОНФЕРЕНЦІЯ
З ФІЗИКИ СЕГНЕТОЕЛЕКТРИКІВ»

Формат 60x84/8. Умовн. друк. арк. 11,16. Зам. № 87. Наклад 100 прим.
Видавництво УжНУ «Говерла».
88000, м. Ужгород, вул. Капітульна, 18. E-mail: hoverla@i.ua

*Свідоцтво про внесення до державного реєстру
видавців, виготівників і розповсюджувачів видавничої продукції –
Серія 3т № 32 від 31 травня 2006 року*

Temperature Sensor Based on $\text{Sn}_2\text{P}_2\text{S}_6$ Crystal

Yu. Tyagur¹, I. Tyagur²

1- Uzhhorod National University, Narodna Square, 3, Uzhhorod, 88000, Ukraine

2- Technical University of Liberec, Halkova 6, 461 17 Liberec I, Czech Republic

irena.tyagur@centrum.cz

In our work, the model of a low temperature sensor is suggested based on temperature dependences of the alternating current at various frequencies of field. For further analysis and calculations measurements of impedance as a function of temperature $Z(T)$ in the interval (5–300) K were used [1].

Temperature dependences of the specific impedance $z_0(T)$ were calculated at frequency 10 kHz:

$$z_0(T) = Z(T) \cdot \left(\frac{S}{d} \right) \quad (1)$$

where $Z(T)$ are experimental values, S is the electrodes area, d is samples thickness (in the direction of Ps , [100]). The value of electric field is:

$$E = U_e / d \quad (2)$$

where $U_e = U_m / \sqrt{2}$ is effective value of electric current, U_m is voltage amplitude. Voltage as a function of time is described mathematically by the following equation (at $f = 10\text{kHz}$):

$$U(t) = U_m \cdot \cos(2\pi ft + \varphi_0) \quad (3)$$

In the further interval, values of the specific impedance sharply decrease with increasing temperature for all three investigated samples in ferroelectric phase. We described experimental dependences of $\log(z_0(T))$ in ferroelectric phase using fourth-order polynomial:

$$\log(z_0(T)) = A(f)_{fe} + B1(f)_{fe} \cdot T + B2(f)_{fe} \cdot T^2 + B3(f)_{fe} \cdot T^3 + B4(f)_{fe} \cdot T^4 \quad (4)$$

where $A(f)_{fe}$, $B1(f)_{fe}$, $B2(f)_{fe}$, $B3(f)_{fe}$, $B4(f)_{fe}$ are coefficients of the equation.

Values of these coefficients are calculated by approximation of experimental dependences of $\log(z_0(T))$. Based on impedance investigations and obtained dependence $\log(z_0(T))$, temperature dependences of the alternating current $I(T)$ are determined for crystals $\text{Sn}_2\text{P}_2\text{S}_6$, $\text{Sn}_2\text{P}_2(\text{Se}_{0.05}\text{S}_{0.95})_6$ and $\text{Sn}_2\text{P}_2\text{Se}_6$. Let the effective voltage $U_e = 10\text{V}$ is applied to the model sample - a square plate with thickness $d = 1\text{mm}$, with circle Au electrodes ($D = 5\text{mm}$), $f = 10\text{kHz}$, then, temperature dependence of the current is calculated by the following equation:

$$I(T) = \frac{U_e}{Z(T)} = \frac{U_e}{51 \cdot \left(10^{(A(f)_{fe} + B1(f)_{fe} \cdot T + B2(f)_{fe} \cdot T^2 + B3(f)_{fe} \cdot T^3 + B4(f)_{fe} \cdot T^4)} \right)} \quad (5)$$

The value of current sharply increases from μA to mA values with increasing temperature for all three samples. The character of $I(T)$ dependences is non-linear in the whole investigated range of temperatures (5–300) K. From our investigations we would like to conclude that $\text{Sn}_2\text{P}_2\text{S}_6$, $\text{Sn}_2\text{P}_2(\text{Se}_{0.05}\text{S}_{0.95})_6$ and $\text{Sn}_2\text{P}_2\text{Se}_6$ crystals are competitive and promising materials for low temperature sensors and sensors of thermal radiation in a wide temperature range from 5 K to 300 K.

	$A(f)_{fe}$, [10 ⁻²]	$B1(f)_{fe}$, [10 ⁻⁴], K ⁻¹	$B2(f)_{fe}$, [10 ⁻⁶], K ⁻²	$B3(f)_{fe}$, [10 ⁻⁸], K ⁻³	$B4(f)_{fe}$, [10 ⁻¹¹], K ⁻⁴
$\text{Sn}_2\text{P}_2\text{S}_6$, 100K ≤ T ≤ 300K, f = 10kHz	(371.1 ± 2.5)	(178 ± 6)	(-168 ± 5)	(65 ± 5)	(-96 ± 3)
$\text{Sn}_2\text{P}_2(\text{Se}_{0.05}\text{S}_{0.95})_6$ 0K ≤ T ≤ 300K, f = 10kHz	(472.5 ± 0.1)	(-19.3 ± 0.5)	(-26.3 ± 0.7)	(16.5 ± 0.3)	(-34.6 ± 0.5)
$\text{Sn}_2\text{P}_2\text{Se}_6$, 0K ≤ T < T _C = 192K f = 10kHz	(458.6 ± 0.3)	(-174 ± 2)	(173 ± 3)	(-89 ± 2)	(133 ± 6)

Tab. I. Approximation coefficients of $\log(z_0(T))$ dependences by fourth-order polynomial in ferroelectric phase for samples at 10 kHz